

PNP Transistors

6501130 NATL SEMICOND, (DISCRETE)

28C 35441 D
T-29-01

LOW LEVEL AMPS



Type No.	Case Style	V _{CB0} (V) Min	V _{CEO} (V) Min	V _{EBO} (V) Min	I _{CB0} @ V _{CB} (mA) Max	h _{FE} @ I _C & V _{CE} (Min Max) (mA) (V)	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	f _T (ns) Max	NF (dB) Max	Test Conditions	Process No.
2N2604	TO-46	60	45	6	10	350 10 60 0.5 40 120 0.01	0.5	0.7 0.9	10	10	6 30	0.5	3	1	62
2N2605	TO-46	60	45	6	10	600 10 150 0.5 100 300 0.01	0.5	0.7 0.9	10	10	6 30	0.5	3	2	62
2N3547	TO-18	60	60	6	25	75 10 100 500 1 60 0.1	1.0	1.0	10	10	8 45	1	5	1	62
2N3548	TO-18	60	45	6	10	600 10 150 0.1 100 300 0.01	1.0	1.0	10	10	8 60 150	1	4	1	62
2N3549	TO-18	60	60	6	10	800 10 200 1 150 0.1 100 500 0.01	1.0	1.0	10	10	8 60 150	1	4	1	62
2N3550	TO-18	60	45	8	1	800 10 300 1 250 0.1 200 600 0.01 125 0.001	0.5	0.7 0.9	5	5	8 60 150	1	4	1	62
2N3799	TO-18	60	60	5	10	300 0.1 300 900 0.5 300 0.1 225 0.01 75 0.001	0.25	0.8	1	1	4 30	0.5	2.5	3	62
2N4058	TO-92 (94)	30	30	6	100	100 400 0.1	0.7		10	10			5	3	62
2N4059	TO-92 (94)	30	30	6	100	45 660 1	0.7		10	10					62
2N4061	TO-92 (94)	30	30	6	100	90 330 1	0.7		10	10					62
2N4062	TO-92 (94)	30	30	6	100	180 660 1	0.7		10	10					62
2N4248	TO-92 (92)	Same as 2N4248, see page 2-7 for explanation													
2N4249	TO-92 (92)	Same as 2N4249, see page 2-7 for explanation													
2N4250	TO-92 (92)	Same as 2N4250, see page 2-7 for explanation													

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LOW LEVEL AMPS (Continued)

Type No.	Case Style	V _{CEO} (V) Min	V _{CE0} (V) Min	V _{BE0} (V) Min	I _{CBO} (nA) Max	V _{CB} (V)	h _{FE} Min	I _C @ Max (mA)	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C @ Max (mA)	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.	
																			Max
2N4250A	TO-92 (92)																	62	
Same as PN4250A, see below for explanation																			
2N4288	TO-92 (94)	30	25	6	50	25	75	10	0.35	0.8	1	1	8	40	1			62	
Same as PN4288, see below for explanation																			
2N4289	TO-92 (94)	60	45	7	10	45	75	10	0.35	0.8	1	1	8	40	1	4	1	62	
Same as PN4289, see below for explanation																			
2N4964	TO-92 (92)						100	0.1										62	
Same as MPSA70, see below for explanation																			
2N4965	TO-92 (92)																	62	
Same as 2N5086, see below for explanation																			
2N5086	TO-92 (92)	50	50		50	35	150	10	0.3		10	10	4	40	0.5	3	4	62	
Same as 2N5086, see below for explanation																			
2N5087	TO-92 (92)	50	50		50	35	150	0.1	0.3		10	10	4	40	0.5	2	4	62	
Same as 2N5087, see below for explanation																			
2N5227	TO-92 (92)	30	30	3	100	10	50	2	0.4	1.0	10	10	5	100	10			62	
Same as 2N5227, see below for explanation																			
MPSA70	TO-92 (92)		40	4	100	30	40	5	0.25		10	10	4	125	5			62	
Same as MPSA70, see below for explanation																			
MPS523	TO-92 (92)		25	4	50	20	300	2	0.5		50	50	4					62	
Same as MPS523, see below for explanation																			
PN4248	TO-92 (92)		40	5	10	40	50	0.1	0.25		10	10	6					62	
Same as PN4248, see below for explanation																			
PN4249	TO-92 (92)		60	5	10	40	100	0.1	0.25		10	10	6					62	
Same as PN4249, see below for explanation																			
PN4250	TO-92 (92)		40	5	10	40	250	0.1	0.25		10	10	6			2	4	62	
Same as PN4250, see below for explanation																			
PN4250A	TO-92 (92)		60	5	10	50	250	0.1	0.25		10	10	6			2	4	62	

TEST CONDITIONS: (1) I_C = 10 μA, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (2) I_C = 10 μA, V_{CE} = 5V, f = 10 kHz. (3) I_C = 100 μA, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (4) I_C = 20 μA, V_{CE} = 5V, f = 10 Hz-15.7 kHz.

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